SLRS021B – DECEMBER 1976 – REVISED SEPTEMBER 1999

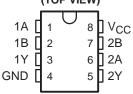
PERIPHERAL DRIVERS FOR HIGH-CURRENT SWITCHING AT VERY HIGH SPEEDS

- Characterized for Use to 300 mA
- High-Voltage Outputs
- No Output Latch-Up at 20 V (After Conducting 300 mA)
- High-Speed Switching
- Circuit Flexibility for Varied Applications
- TTL-Compatible Diode-Clamped Inputs
- Standard Supply Voltages
- Plastic DIP (P) With Copper Lead Frame Provides Cooler Operation and Improved Reliability
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

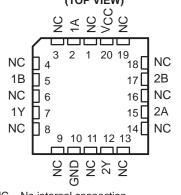
DEVICE	LOGIC OF COMPLETE CIRCUIT	PACKAGES								
SN55451B	AND	FK, JG								
SN55452B	NAND	JG								
SN55453B	OR	FK, JG								
SN55454B	NOR	JG								
SN75451B	AND	D, P								
SN75452B	NAND	D, P								
SN75453B	OR	D, P								
SN75454B	NOR	D, P								

SUMMARY OF DEVICES

SN55451B, SN55452B, SN55453B, SN55454B . . . JG PACKAGE SN75451B, SN75452B, SN75453B, SN75454B . . . D OR P PACKAGE (TOP VIEW)







NC - No internal connection

description

The SN55451B through SN55454B and SN75451B through SN75454B are dual peripheral drivers designed for use in systems that employ TTL logic. This family is functionally interchangeable with and replaces the SN75450 family and the SN75450A family devices manufactured previously. The speed of the devices is equal to that of the SN75450 family, and the parts are designed to ensure freedom from latch-up. Diode-clamped inputs simplify circuit design. Typical applications include high-speed logic buffers, power drivers, relay drivers, lamp drivers, MOS drivers, line drivers, and memory drivers.

The SN55451B/SN75451B, SN55452B/SN75452B, SN55453B/SN75453B, and SN55454B/SN75454B are dual peripheral AND, NAND, OR, and NOR drivers, respectively (assuming positive logic), with the output of the logic gates internally connected to the bases of the npn output transistors.

The SN55' drivers are characterized for operation over the full military range of -55° C to 125° C. The SN75' drivers are characterized for operation from 0° C to 70° C.



SLRS021B – DECEMBER 1976 – REVISED SEPTEMBER 1999

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		SN55'	SN75'	UNIT		
Supply voltage, V _{CC} (see Note 1)		7	7	V		
Input voltage, VI		5.5	5.5	V		
Inter-emitter voltage (see Note 2)	5.5	5.5	V			
Off-state output voltage, VO	30	30	V			
Continuous collector or output current, IOK (see Note 3)	400	400	mA			
Peak collector or output current, II (t_W \leq 10 ms, duty cycle \leq 50%, s	ee Note 4)	500	500	mA		
Continuous total power dissipation		See Diss	See Dissipation Rating Table			
Operating free-air temperature range, TA		-55 to 125	0 to 70	°C		
Storage temperature range, T _{Stg}		-65 to 150	-65 to 150	°C		
Case temperature for 60 seconds	ds FK package 260			°C		
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300		°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package		260	°C		

NOTES: 1. Voltage values are with respect to network GND, unless otherwise specified.

2. This is the voltage between two emitters of a multiple-emitter transistor.

3. This value applies when the base-emitter resistance (R_{BF}) is equal to or less than 500 Ω .

4. Both halves of these dual circuits may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation rating.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	—
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	_

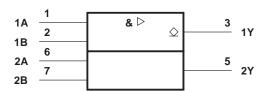
recommended operating conditions

		SN55'			SN75'		UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level input voltage, V _{IH}	2			2			V
Low-level input voltage, VIL			0.8			0.8	V
Operating free-air temperature, T _A	-55		125	0		70	°C



SLRS021B - DECEMBER 1976 - REVISED SEPTEMBER 1999

logic symbol[†]

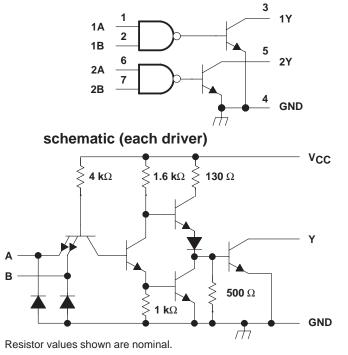


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.

F	FUNCTION TABLE (each driver)										
Α	В	Y									
L	L	L (on state)									
L	н	L (on state)									
Н	L	L (on state)									
Н	Н	H (off state)									
	e logic: AB or										

logic diagram (positive logic)



electrical characteristics over recommended operating free-air temperature range

	PARAMETER	TEAT OON		S	N55451E	3	S	N75451E	3	UNIT
	PARAMETER	TESTCON	TEST CONDITIONS [‡]		TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	lj = -12 mA		-1.2	-1.5		-1.2	-1.5	V
Max		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	V _{IL} = 0.8 V,		0.25	0.5		0.25	0.4	V
V _{OL} L	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	V _{IL} = 0.8 V,		0.5	0.8		0.5	0.7	V
ЮН	High-level output current	$V_{CC} = MIN,$ $V_{OH} = 30 V$	V _{IH} = MIN,			300			100	μΑ
Ц	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
Ιн	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μA
Ι _{ΙL}	Low-level input current	V _{CC} = MAX,	$V_{ } = 0.4 V$		-1	-1.6		-1	-1.6	mA
ІССН	Supply current, outputs high	$V_{CC} = MAX,$	V _I = 5 V		7	11		7	11	mA
ICCL	Supply current, outputs low	V _{CC} = MAX,	$V_{I} = 0$		52	65		52	65	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER		TEST CO	MIN	ТҮР	MAX	UNIT	
^t PLH	Propagation delay time, low-to-high-level	output				18	25	
^t PHL	Propagation delay time, high-to-low-level	n delay time, high-to-low-level output		C _L = 15 pF,		18	25	-
^t TLH	Transition time, low-to-high-level output	ition time, low-to-high-level output		See Figure 1		5	8	ns
t THL	Transition time, high-to-low-level output]			7	12	
Val	High lovel output voltage offer switching	SN55451B	V _S = 20 V,	l _O ≈ 300 mA,		Vg-6.5		mV
∨он	High-level output voltage after switching	SN75451B	See Figure 2	-	Vg-6.5			IIIV



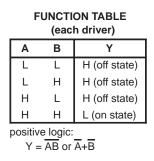
SLRS021B – DECEMBER 1976 – REVISED SEPTEMBER 1999

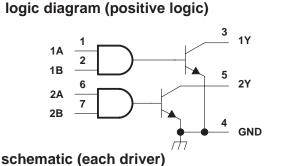
logic symbol[†]

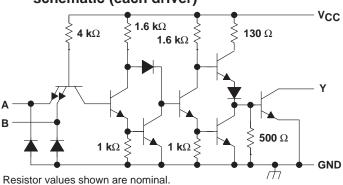


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.







electrical characteristics over recommended operating free-air temperature range

Α

	DADAMETED	TEAT OON		5	SN55452E	3	S	N75452E	3	UNIT
	PARAMETER	TEST CONDITIONS [‡]		MIN	TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	$I_{I} = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
Vei		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	$V_{IH} = MIN,$		0.25	0.5		0.25	0.4	V
V _{OL} Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	$V_{IH} = MIN,$		0.5	0.8		0.5	0.7	V	
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	V _{IL} = 0.8 V,			300			100	μA
Ц	Input current at maximum input voltage	$V_{CC} = MAX,$	$V_{I} = 5.5 V$			1			1	mA
Чн	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μA
Ι _{ΙL}	Low-level input current	$V_{CC} = MAX,$	V _I = 0.4 V		-1.1	-1.6		-1.1	-1.6	mA
ІССН	Supply current, outputs high	V _{CC} = MAX,	V _I = 0		11	14		11	14	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX,$	V _I = 5 V		56	71		56	71	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	PARAMETER			TEST CONDITIONS			MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output					26	35	
^t PHL	Propagation delay time, high-to-low-level output		I _O ≈ 200 mA,			24	35	-
^t TLH	Transition time, low-to-high-level output	Transition time, low-to-high-level output		See Figure 1		5	8	ns
^t THL	Transition time, high-to-low-level output					7	12	
Val	High lovel output voltage ofter outphing	SN55452B	V _S = 20 V,	l _O ≈ 300 mA,		Vg-6.5		mV
∨он	High-level output voltage after switching	SN75452B	See Figure 2	-	V _S -6.5			mv



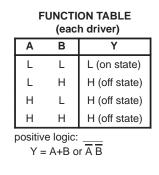
SLRS021B - DECEMBER 1976 - REVISED SEPTEMBER 1999

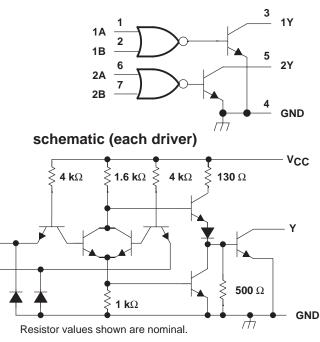
logic symbol[†]



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.





logic diagram (positive logic)

electrical characteristics over recommended operating free-air temperature range

B

	DADAMETER	7507.000		5	SN55453E	3	5	SN75453E	3	LINUT
	PARAMETER	TESTCON	TEST CONDITIONS [‡]		TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	l _l = –12 mA		-1.2	-1.5		-1.2	-1.5	V
) ($V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	V _{IL} = 0.8 V,		0.25	0.5		0.25	0.4	V
VOL	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	V _{IL} = 0.8 V,		0.5	0.8		0.5	0.7	v
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	VIH = MIN,			300			100	μΑ
lj	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
IIH	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μΑ
۱ _{IL}	Low-level input current	$V_{CC} = MAX,$	V _I = 0.4 V		-1	-1.6		-1	-1.6	mA
Іссн	Supply current, outputs high	$V_{CC} = MAX,$	V _I = 5 V		8	11		8	11	mA
ICCL	Supply current, outputs low	V _{CC} = MAX,	V _I = 0		54	68		54	68	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25° C.

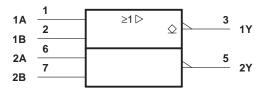
switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	PARAMETER			TEST CONDITIONS			MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level	output				18	25	
^t PHL	Propagation delay time, high-to-low-level	ay time, high-to-low-level output		CL = 15 pF,		18	25	50
^t TLH	Transition time, low-to-high-level output			See Figure 1		5	8	ns
^t THL	Transition time, high-to-low-level output		1			7	12	
Varia	Ligh lovel output veltage ofter outphing	SN55453B	V _S = 20 V,	l _O ≈ 300 mA,		V _S -6.5		
∨он	High-level output voltage after switching	SN75453B	See Figure 2		Vg-6.5			mV



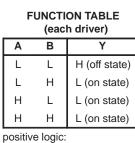
SLRS021B – DECEMBER 1976 – REVISED SEPTEMBER 1999

logic symbol[†]

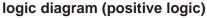


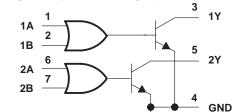
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.



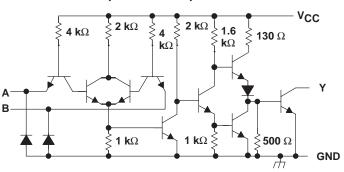
 $Y = \overline{A+B} \text{ or } \overline{AB}$





h

schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

	PARAMETER	TEST CON	DITIONS	S	N55454E	3	S	N75454E	3	UNIT
	PARAMETER	TEST CON	TEST CONDITIONS [‡]		TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	lj = -12 mA		-1.2	-1.5		-1.2	-1.5	V
Vei		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	VIH = MIN,		0.25	0.5		0.25	0.4	V
VOL	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	VIH = MIN,		0.5	0.8		0.5	0.7	V
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	VIL = 0.8 V,			300			100	μA
Ιį	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
Iн	High-level input current	$V_{CC} = MAX,$	VI = 2.4 V			40			40	μA
١ _L	Low-level input current	$V_{CC} = MAX,$	V _I = 0.4 V		-1	-1.6		-1	-1.6	mA
Іссн	Supply current, outputs high	V _{CC} = MAX,	V _I = 0		13	17		13	17	mA
ICCL	Supply current, outputs low	V _{CC} = MAX,	V _I = 5 V		61	79		61	79	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

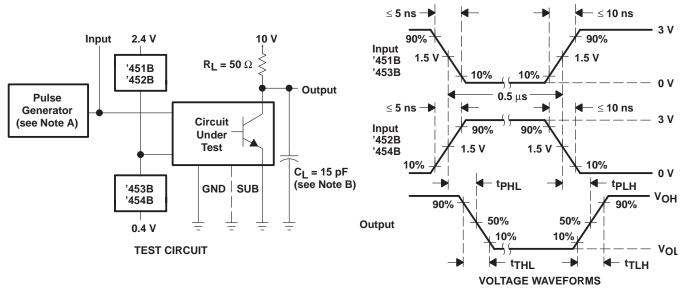
§ All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	PARAMETER	TEST CO	MIN	TYP	MAX	UNIT		
^t PLH	Propagation delay time, low-to-high-level output				27	35		
^t PHL	Propagation delay time, high-to-low-level output	I _O ≈ 200 mA,	CL = 15 pF,		24	35		
^t TLH	Transition time, low-to-high-level output	$R_L = 50 \Omega$,	See Figure 1		5	8	ns	
^t THL	Transition time, high-to-low-level output				7	12		
Val	High-level output voltage after switching	SN55454B	V _S = 20 V,	I _O ≈ 300 mA,		Vg-6.5		mV
VOH	High-level output voltage after switching	SN75454B	See Figure 2		V _S -6.5			IIIV



SLRS021B – DECEMBER 1976 – REVISED SEPTEMBER 1999



PARAMETER MEASUREMENT INFORMATION

NOTES: A. The pulse generator has the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω . B. C_L includes probe and jig capacitance.

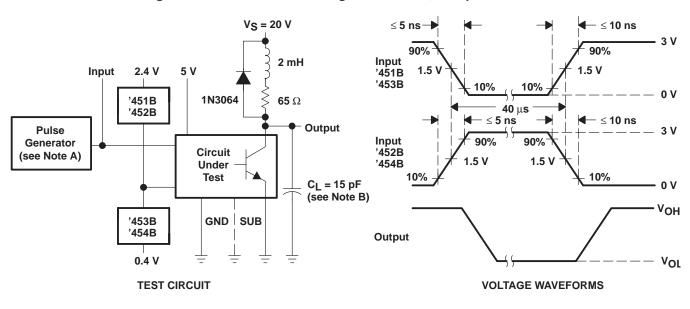


Figure 1. Test Circuit and Voltage Waveforms, Complete Drivers

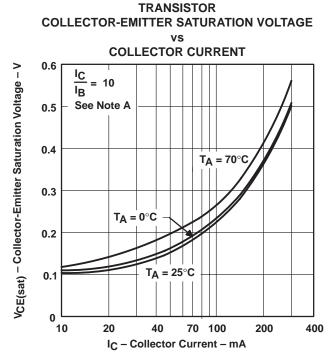
NOTES: A. The pulse generator has the following characteristics: PRR \leq 12.5 kHz, Z_O = 50 $\Omega.$ B. CL includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms for Latch-Up Test of Complete Drivers



SLRS021B – DECEMBER 1976 – REVISED SEPTEMBER 1999





NOTE A: These parameters must be measured using pulse techniques, t_{W} = 300 µs, duty cycle $\leq 2\%.$

Figure 3



www.ti.com

15-Oct-2009

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-9563301Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9563301QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
77049012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
7704901PA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
77049022A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
7704902PA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
JM38510/12902BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
JM38510/12903BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
JM38510/12905BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SN55451BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SN55452BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SN55453BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SN55454BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SN75451BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75451BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75451BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75451BPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75452BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

PACKAGE OPTION ADDENDUM

TEXAS INSTRUMENTS

www.ti.com

15-Oct-2009

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽
SN75452BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75452BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75452BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
SN75452BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75452BPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75453BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75453BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75453BPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75454BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75454BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75454BDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75454BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75454BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75454BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75454BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75454BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75454BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI
SN75454BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLI

V INSTRUMENTS

15-Oct-2009

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75454BPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SNJ55451BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ55451BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SNJ55452BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ55452BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SNJ55453BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ55453BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SNJ55454BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ55454BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

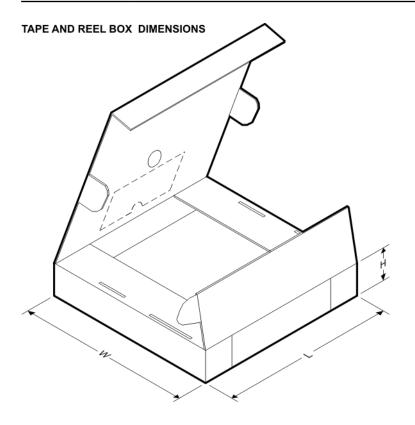


*All dimensions are nomina Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75451BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75451BPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75452BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75452BPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75453BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75453BPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75454BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75454BPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75451BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75451BPSR	SO	PS	8	2000	346.0	346.0	33.0
SN75452BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75452BPSR	SO	PS	8	2000	346.0	346.0	33.0
SN75453BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75453BPSR	SO	PS	8	2000	346.0	346.0	33.0
SN75454BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75454BPSR	SO	PS	8	2000	346.0	346.0	33.0

MECHANICAL DATA

MCER001A - JANUARY 1995 - REVISED JANUARY 1997



CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8



LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N**) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. This package can be hermetically sealed with a metal lid.

D. Falls within JEDEC MS-004



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Audio	www.ti.com/audio	Communications and Telecom	www.ti.com/communications
Amplifiers	amplifier.ti.com	Computers and Peripherals	www.ti.com/computers
Data Converters	dataconverter.ti.com	Consumer Electronics	www.ti.com/consumer-apps
DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy
DSP	dsp.ti.com	Industrial	www.ti.com/industrial
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Security	www.ti.com/security
Logic	logic.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Power Mgmt	power.ti.com	Transportation and Automotive	www.ti.com/automotive
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com	Wireless	www.ti.com/wireless-apps
RF/IF and ZigBee® Solutions	www.ti.com/lprf		

TI E2E Community Home Page

e2e.ti.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated